

PUSH-PULL FOUR CHANNEL DRIVER WITH DIODES

600mA OUTPUT CURRENT CAPABILITY PER CHANNEL

1.2A PEAK OUTPUT CURRENT (non repetitive) PER CHANNEL

ENABLE FACILITY

OVERTEMPERATURE PROTECTION

LOGICAL "0" INPUT VOLTAGE UP TO 1.5 V (HIGH NOISE IMMUNITY)

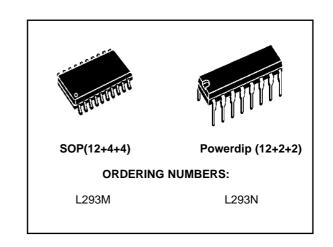
INTERNAL CLAMP DIODES

DESCRIPTION

The Device is a monolithic integrated high voltage, high current four channel driver designed to accept standard DTL or TTL logic levels and drive inductive loads (such as relays solenoides, DC and stepping motors) and switching power transistors.

To simplify use as two bridges each pair of channels is equipped with an enable input. A separate supply input is provided for the logic, allowing operation at a lower voltage and internal clamp diodes are included.

This device is suitable for use in switching applications at frequencies up to 5 kHz.



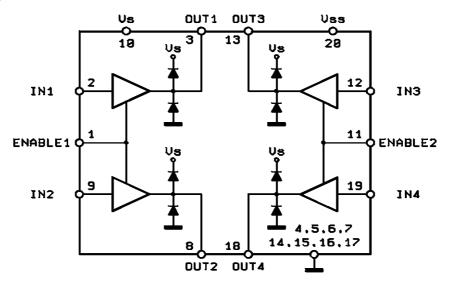
The L293D is assembled in a 16 lead plastic packaage which has 4 center pins connected together and used for heatsinking

The L293DD is assembled in a 20 lead surface mount which has 8 center pins connected together and used for heatsinking.

ORDERING INFORMATION

| DEVICE | Package Type | MARKING | Packing | Packing Qty |
|--------|--------------|---------|---------|-------------|
| L293N | DIP16 | L293D | TUBE | 1000/box |
| L293M/ | SOP20 | L293DD | REEL | 2000/reel |

BLOCK DIAGRAM

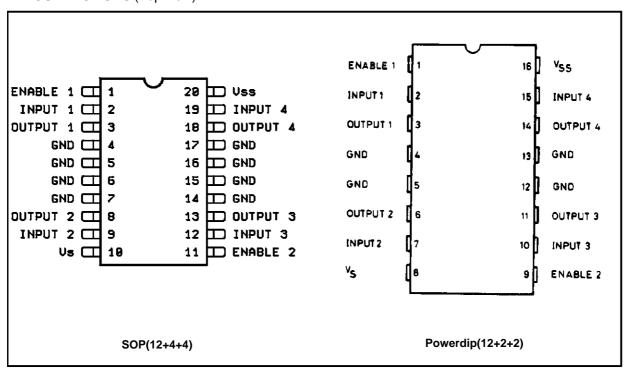




ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------|--|-------------|------|
| Vs | Supply Voltage | 36 | V |
| V _{SS} | Logic Supply Voltage | 36 | V |
| Vi | Input Voltage | 7 | V |
| V _{en} | Enable Voltage | 7 | V |
| Io | Peak Output Current (100 μs non repetitive) | 1.2 | Α |
| P _{tot} | Total Power Dissipation at T _{pins} = 90 °C | 4 | W |
| T_{stg} , T_j | Storage and Junction Temperature | - 40 to 150 | °C |

PIN CONNECTIONS (Top view)



THERMAL DATA

| Symbol | Decription | DIP | SOP | Unit |
|------------------------|--|-----|--------|------|
| R _{th j-pins} | Thermal Resistance Junction-pins max. | _ | 14 | °C/W |
| R _{th j-amb} | Thermal Resistance junction-ambient max. | 80 | 50 (*) | °C/W |
| R _{th j-case} | Thermal Resistance Junction-case max. | 14 | - | |

^(*) With 6sq. cm on board heatsink.



ELECTRICAL CHARACTERISTICS (for each channel, $V_S = 24 \text{ V}$, $V_{SS} = 5 \text{ V}$, $T_{amb} = 25 ^{\circ}\text{C}$, unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min. | Тур. | Max. | Unit |
|-----------------------|---|---|-----------------|------|-----------------|------|
| Vs | Supply Voltage (pin 10) | | V _{SS} | | 36 | V |
| V_{SS} | Logic Supply Voltage (pin 20) | | 4.5 | | 36 | V |
| I _S | Total Quiescent Supply Current | $V_i = L$; $I_O = 0$; $V_{en} = H$ | | 2 | 6 | mA |
| | (pin 10) | $V_i = H$; $I_O = 0$; $V_{en} = H$ | | 16 | 24 | mA |
| | | V _{en} = L | | | 4 | mA |
| I _{SS} | Total Quiescent Logic Supply | $V_i = L$; $I_O = 0$; $V_{en} = H$ | | 44 | 60 | mA |
| | Current (pin 20) | $V_i = H$; $I_O = 0$; $V_{en} = H$ | | 16 | 22 | mA |
| | | V _{en} = L | | 16 | 24 | mA |
| V_{IL} | Input Low Voltage (pin 2, 9, 12, 19) | | -0.3 | | 1.5 | ٧ |
| V_{IH} | Input High Voltage (pin 2, 9, | V _{SS} ≤ 7 V | 2.3 | | V _{SS} | V |
| | 12, 19) | V _{SS} > 7 V | 2.3 | | 7 | V |
| I _{IL} | Low Voltage Input Current (pin 2, 9, 12, 19) | V _{IL} = 1.5 V | | | - 10 | μА |
| Іін | High Voltage Input Current (pin 2, 9, 12, 19) | $2.3~\text{V} \leq \text{V}_{\text{IH}} \leq \text{V}_{\text{SS}} - 0.6~\text{V}$ | | 30 | 100 | μА |
| V _{en L} | Enable Low Voltage (pin 1, 11) | | -0.3 | | 1.5 | V |
| V _{en H} | Enable High Voltage | V _{SS} ≤ 7 V | 2.3 | | V_{SS} | V |
| | (pin 1, 11) | V _{SS} > 7 V | 2.3 | | 7 | V |
| l _{en L} | Low Voltage Enable Current (pin 1, 11) | V _{en L} = 1.5 V | | - 30 | - 100 | μА |
| l _{en H} | High Voltage Enable Current (pin 1, 11) | $2.3~\text{V} \leq \text{V}_{\text{en H}} \leq \text{V}_{\text{SS}} - 0.6~\text{V}$ | | | ± 10 | μА |
| V _{CE(sat)H} | Source Output Saturation Voltage (pins 3, 8, 13, 18) | $I_{O} = -0.6 \text{ A}$ | | 1.4 | 1.8 | V |
| $V_{\text{CE(sat)L}}$ | Sink Output Saturation Voltage (pins 3, 8, 13, 18) | I _O = + 0.6 A | | 1.2 | 1.8 | V |
| V_{F} | Clamp Diode Forward Voltage | I _O = 600nA | | 1.3 | | V |
| t _r | Rise Time (*) | 0.1 to 0.9 V _O | | 250 | | ns |
| t _f | Fall Time (*) | 0.9 to 0.1 V _O | | 250 | | ns |
| t _{on} | Turn-on Delay (*) | 0.5 V _i to 0.5 V _O | | 750 | | ns |
| t _{off} | Turn-off Delay (*) | 0.5 V _i to 0.5 V _O | | 200 | | ns |

^(*) See fig. 1.



TRUTH TABLE (one channel)

| Input | Enable (*) | Output | |
|-------|------------|--------|--|
| Н | Н | Н | |
| L | Н | L | |
| Н | L | Z | |
| L | L | Z | |

Z = High output impedance

Figure 1: Switching Times

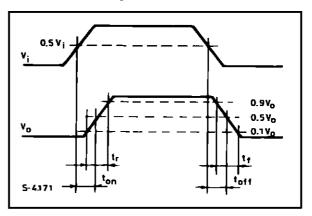
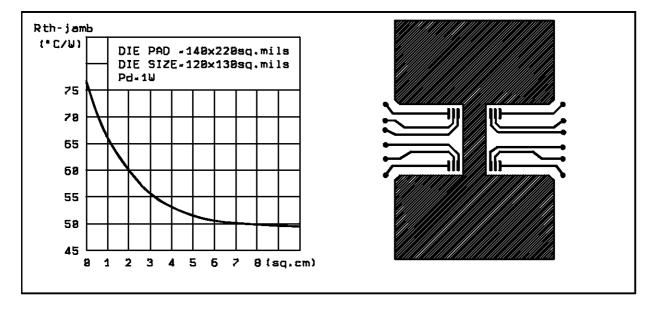


Figure 2: Junction to ambient thermal resistance vs. area on board heatsink (SOP12+4+4 package)



^(*) Relative to the considered channel



Important statement:

Huaguan Semiconductor Co,Ltd. reserves the right to change the products and services provided without notice. Customers should obtain the latest relevant information before ordering, and verify the timeliness and accuracy of this information.

Customers are responsible for complying with safety standards and taking safety measures when using our products for system design and machine manufacturing to avoid potential risks that may result in personal injury or property damage.

Our products are not licensed for applications in life support, military, aerospace, etc., so we do not bear the consequences of the application of these products in these fields.

Our documentation is only permitted to be copied without any tampering with the content, so we do not accept any responsibility or liability for the altered documents.

http://www.hgsemi.com.cn 5 2018 AUG